imall

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Contact us

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ZVNL120G

Product Summary

V _(BR) dss	Rds(on)	Ι _D Τ _A = +25°C
200V	10Ω @ V _{GS} = 10V	320mA

Description

This new generation trench MOSFET features a unique structure combining the benefits of low on-resistance and fast switching, making it ideal for high efficiency power management applications.

Applications

• Off-line Power Supply Start-up Circuitry

200V N-CHANNEL ENHANCEMENT MODE MOSFET

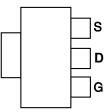
Features and Benefits

- High Voltage
- Low On-resistance
- Fast Switching Speed
- Low Gate Drive
- Low Threshold
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

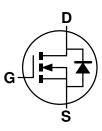
Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish (3)
- Weight: 0.112 grams (Approximate)









Equivalent Circuit

Ordering Information (Note 4)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZVNL120GTA	ZVNL120	7	12	1,000
ZVNL120GTC	ZVNL120	13	12	4,000

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

D

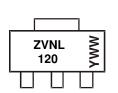
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

Notes:



SOT223

ZVNL120 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 5 = 2015) WW or \overline{WW} = Week Code (01~53)



Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V _{DSS}	200	V
Gate-Source Voltage	V _{GSS}	±20	V
Continuous Drain Current (V _{GS} = 10V, T _A = +25°C)	I _D	320	mA
Pulsed Drain Current	I _{DM}	2	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation at $T_A = +25^{\circ}C$ (Note 5)	PD	2.0	W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS					•	·	
Drain-Source Breakdown Voltage	BV _{DSS}	200	-	-	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	I _{DSS}	-	-	10 100	μA	$V_{DS} = 200V, V_{GS} = 0V$ $V_{DS} = 160V, V_{GS} = 0V, T = +125^{\circ}C$	
Gate-Source Leakage	IGSS	-	-	100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS					•	·	
Gate Threshold Voltage	V _{GS(TH)}	0.5	-	1.5	V	$V_{DS} = V_{GS}, I_D = 1mA$	
Static Drain-Source On-Resistance (Note 6)	_	-	-	10	Ω	$V_{GS} = 5V, I_D = 250mA$	
Static Drain-Source On-Resistance (Note 6)	R _{DS(ON)}	-	-	10	Ω	$V_{GS} = 3V, I_D = 125mA$	
Forward Transconductance (Notes 6 & 7)	g fs	200	-	-	mS	$V_{DS} = 25V, I_D = 250mA$	
On-State Drain Current (Note 6)	I _{D(ON)}	500	-	-	mA	V _{DS} = 25V, V _{GS} = 5V	
DYNAMIC CHARACTERISTICS (Note 7)						·	
Input Capacitance	Ciss	-	-	85	pF	V _{DS} = 25V, V _{GS} = 0V, f = 1.0MHz	
Output Capacitance	Coss	-	-	20	pF		
Reverse Transfer Capacitance	Crss	-	-	7	pF		
Turn-On Delay Time (Note 8)	t _{D(ON)}	-	-	8	ns		
Turn-On Rise Time (Note 8)	t _R	-	-	8	ns		
Turn-Off Delay Time (Note 8)	t _{D(OFF)}	-	-	20	ns	V _{DD} = 25V, I _D = 250mA	
Turn-Off Fall Time (Note 8)	t _F	-	-	12	ns		

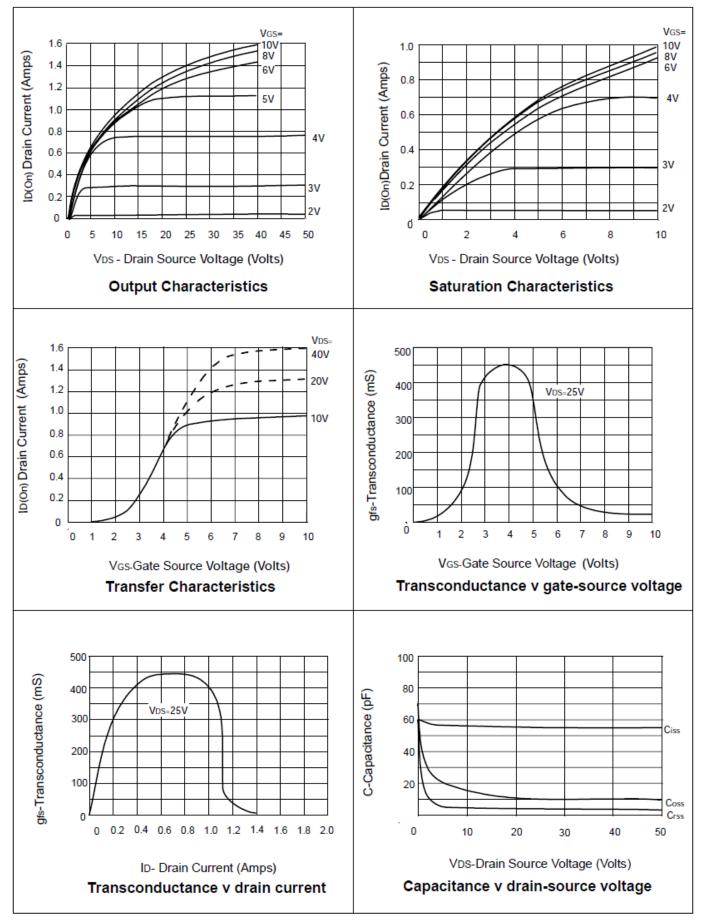
6. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.

7. Sample test.

8. Switching times measured with 50 $\!\Omega$ source impedance and <5ns rise time on a pulse generator.

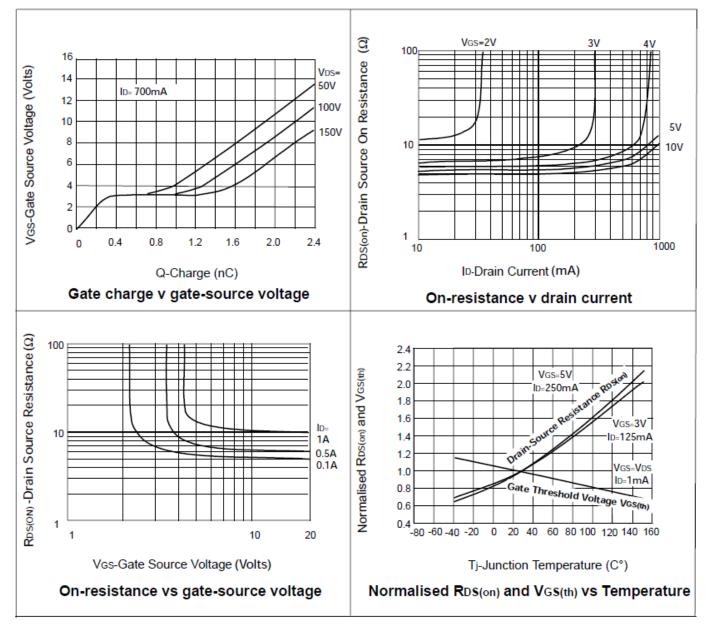


ZVNL120G





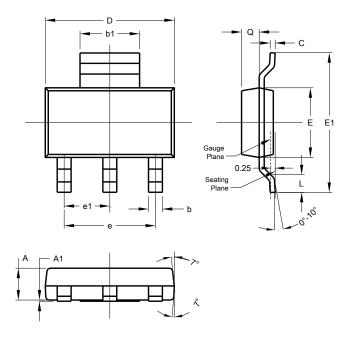






Package Outline Dimensions

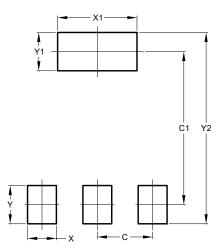
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



	SOT223					
Dim	Min	Max	Тур			
Α	1.55	1.65	1.60			
A1	0.010	0.15	0.05			
b	0.60	0.80	0.70			
b1	2.90	3.10	3.00			
С	0.20	0.30	0.25			
D	6.45	6.55	6.50			
Е	3.45	3.55	3.50			
E1	6.90	7.10	7.00			
е	-	-	4.60			
e1	-	-	2.30			
L	0.85	1.05	0.95			
Q	0.84	0.94	0.89			
All I	All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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